
Electronic transport in topological insulators

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Overview

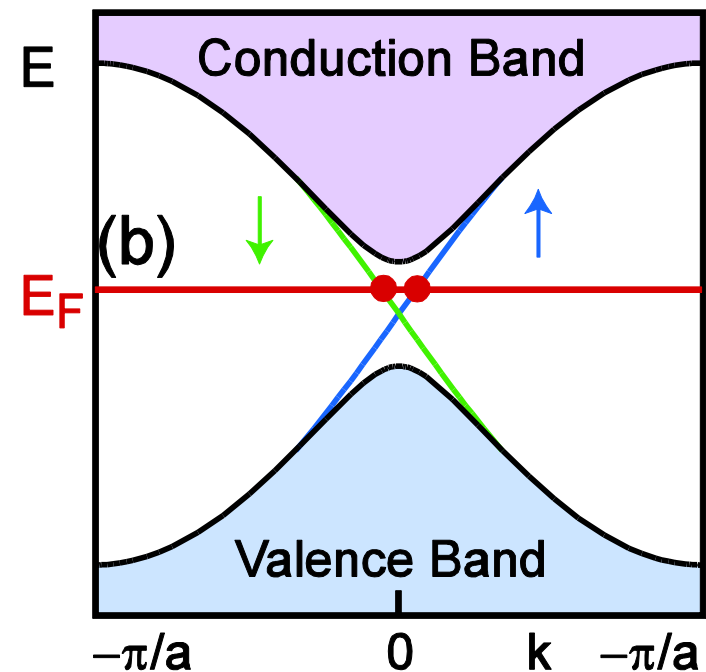
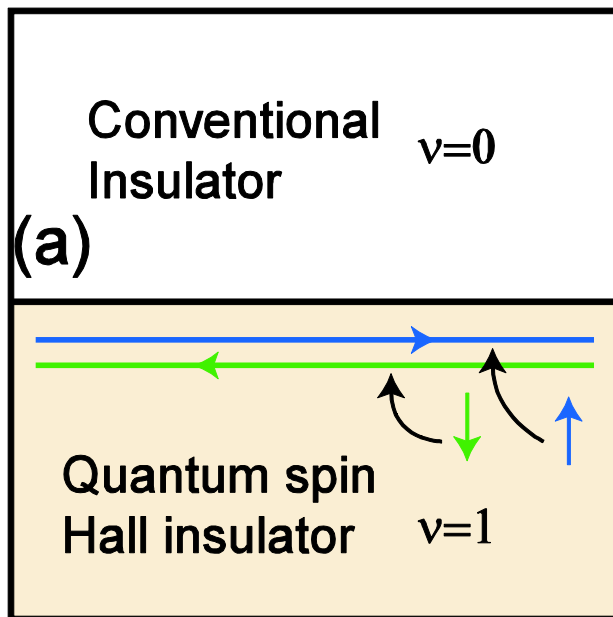
- Brief intro to Topological Insulators (TI)
M.Z. Hasan & C.L. Kane, Rev. Mod. Phys. 82, 3045 (2010)
 - Helical Luttinger liquid in TI nanowires
RE, A. Zazunov & A. Levy Yeyati, PRL 105, 136403 (2010)
 - Coulomb blockade of Majorana fermion induced transport
A. Zazunov, A. Levy Yeyati & RE, PRB 84, 165440 (2011)
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Topological Insulator

- Recently discovered new state of matter
 - Bulk band gap like ordinary insulator, but **band inversion** due to **strong spin orbit coupling**
 - **Time reversal symmetry: topological protection of gapless modes at surface**
- 2D „**quantum spin Hall**“ TI: helical edge states
 - Close cousin of integer quantum Hall state
 - Initially predicted for graphene *Kane & Mele, PRL 2005*
 - observed in HgTe quantum wells *König et al., Science 2007*
- 3D „**strong**“ **topological insulator**
 - Predicted independently by three groups *Moore & Balents, PRB 2007; Fu, Kane & Mele, PRL 2007; Roy, PRB 2009*
 - First observed via ARPES, present reference material is Bi_2Se_3 *Hasan & Kane, RMP 2010*

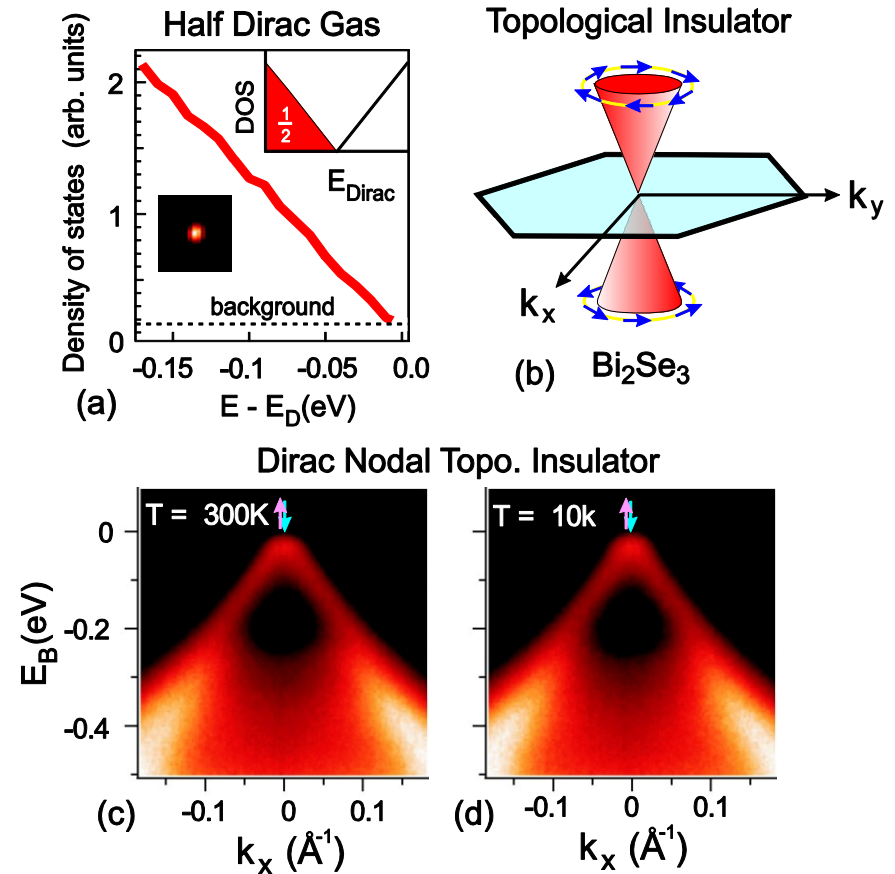
Helical edge state of 2D TI

... up and down spins propagate in different direction:
a peculiar new spin-filtered 1D liquid



2D massless Dirac fermions as surface states of 3D topological insulators

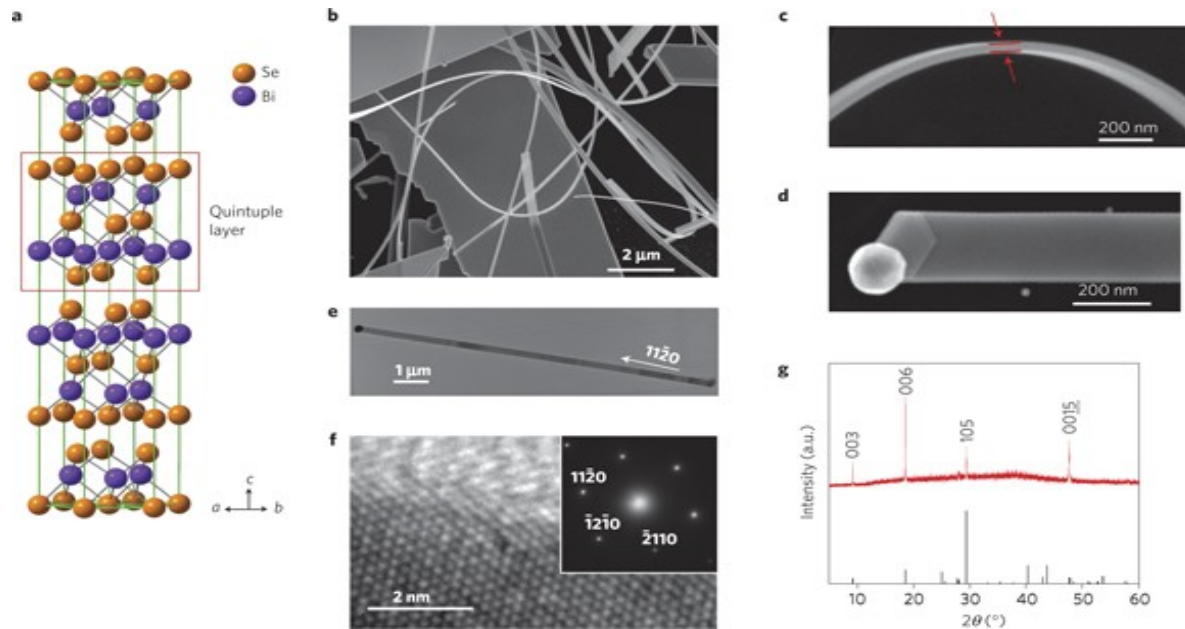
- Map from Brillouin zone to Hilbert space has nontrivial topology
- Mathematically characterized by Z_2 invariant
- Avoid fermion doubling theorem
- Spin momentum locking
- Observed by ARPES in Bi_2Se_3



Bi₂Se₃ nanowires: fabrication

Rhombohedral phase,
space group D_{3d}^5

Au catalysed VLS growth



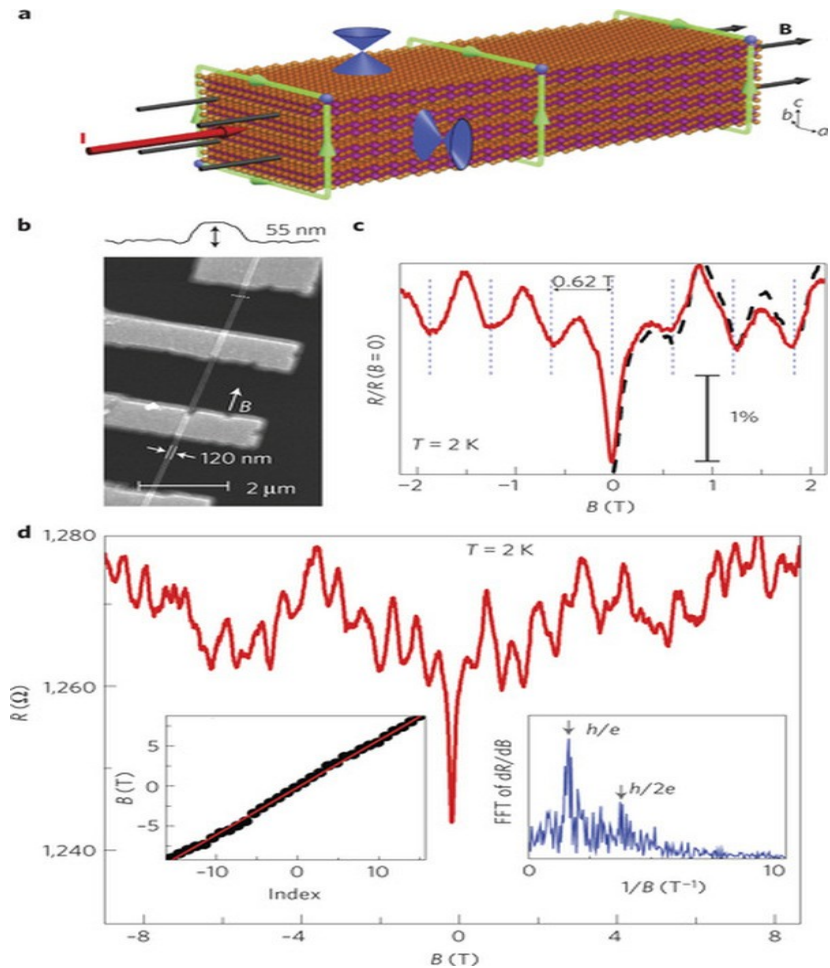
Peng et al. (Stanford), Nature Materials 2010

Surface state in transport experiments

Clear evidence for the surface state:
Aharonov-Bohm oscillations of conductance

- Upper bound for surface state width: 6 nm

Peng et al., Nat. Mat. 2010



TI nanowires: theory

Egger, Zazunov & Levy Yeyati, PRL 2010

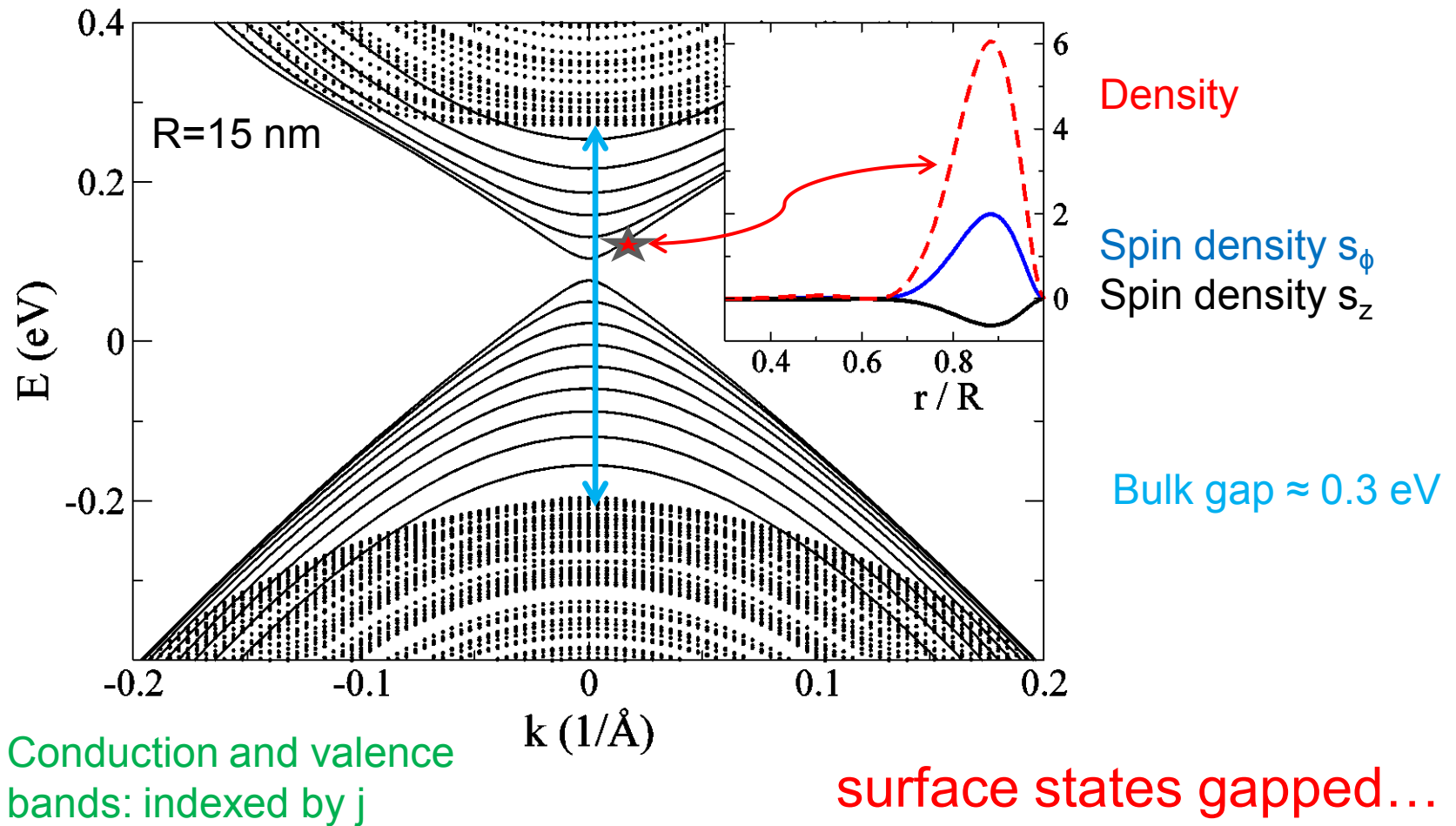
- Consider strong TI material (e.g. Bi_2Se_3): cylindrical nanowire of radius R
- Bandstructure from **kp** approach

Zhang et al., Nature Phys. 2009

- anisotropy axis $\parallel z$: conserved **momentum k**
- Rotational xy symmetry: total angular momentum conservation, $J_z = -i\partial_\phi + \sigma_z / 2 \rightarrow$ **half-integer j**
- Wave function vanishes at boundary $r=R$: expand in orthonormal set of radial functions

$$u_{nj}(r) = \frac{\sqrt{2} J_{j-1/2}(\gamma_{n,j-1/2} r/R)}{R J_{j+1/2}(\gamma_{n,j-1/2})}$$

Bandstructure of TI nanowire



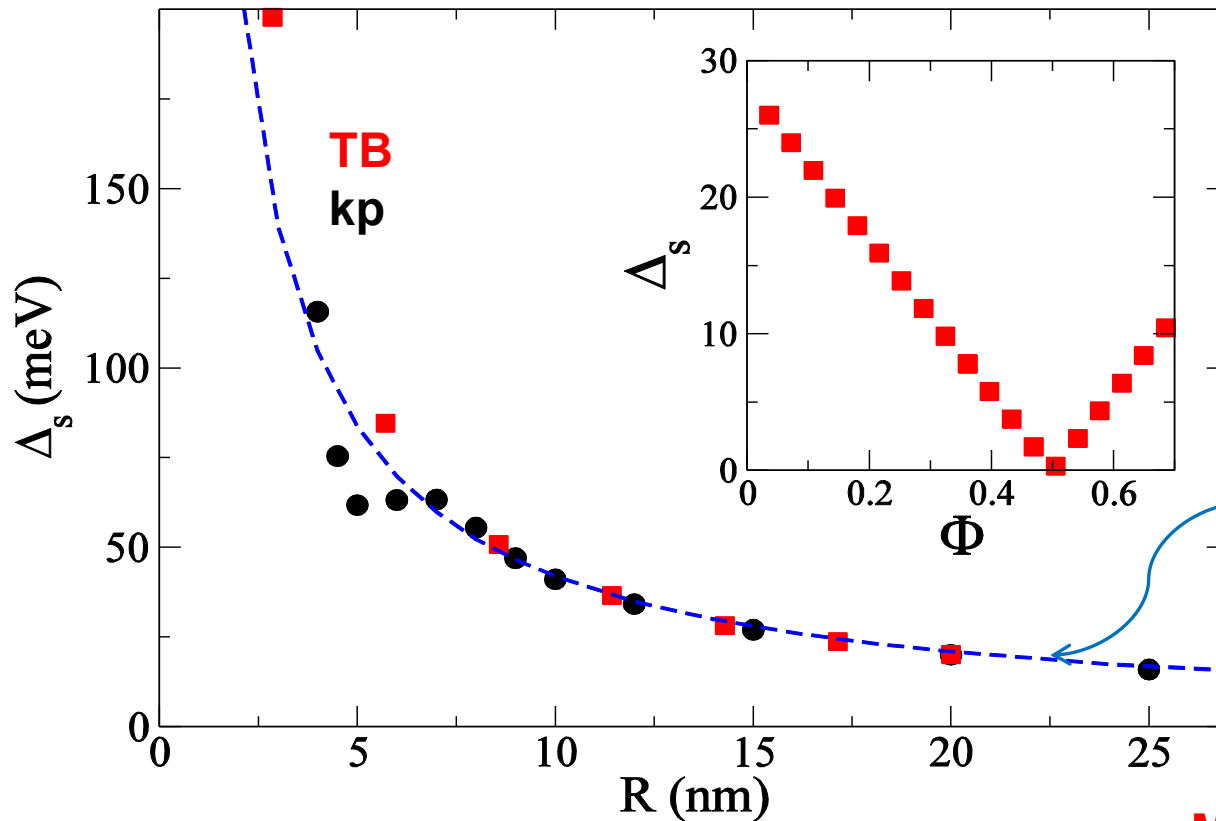
Properties of surface states

- Kramers degeneracy: $E_{-j}(-k) = E_j(k)$
- Inversion symmetry: $E_{-j}(k) = E_j(k)$
- Qualitatively same results from tight-binding calculations
- **Spin-momentum locking**: Local spin is always oriented **tangential to surface** and **perpendicular to momentum**

$$\vec{s} \perp k\hat{e}_z + \frac{j}{R}\hat{e}_\phi \perp \hat{e}_r$$

- Large $|k|$: R-mover counterclockwise spin-polarized
L-mover clockwise spin-polarized

Surface gap



Dirac fermion
description yields

$$\Delta_s = \frac{\hbar v_{\perp}}{R}$$

Magnetic flux can
close the surface gap!

Analytical description

- Surface states well described by **2D massless Dirac fermions** on cylinder surface

Zhang & Vishwanath PRL 2010

- spin-momentum locking, spin direction tangential to surface
- Dirac Hamiltonian in curved space:

$$H = -i\hbar v_F [\alpha^1 D_1 + \alpha^2 D_2] \quad \alpha^{i=\phi,z} = \hat{e}_i \cdot \vec{\sigma}$$

- Covariant derivative: $D_i = \partial_i + \Gamma_i$
- Spin connection defined via relation involving Christoffel symbols $[\Gamma_i, \alpha^j] = \partial_i \alpha^j + \Gamma_{ik}^j \alpha^k$

Surface Dirac fermion theory

- Take into account anisotropy & dim.less flux
... yields **surface Hamiltonian**

$$H_{surf} = e^{-i\sigma_z\phi/2} \left[\hbar v_{\parallel} k \sigma_y - \frac{\hbar v_{\perp}}{R} \sigma_z (-i\partial_{\phi} + \Phi) \right] e^{i\sigma_z\phi/2}$$

- Now perform unitary transformation $U = e^{-i\sigma_z\phi/2}$
- Then: **antiperiodic boundary conditions** around circumference, i.e., **half-integer j**
- Dispersion relation: **waveguide modes**

$$E_{\pm,j}(k) = \pm \sqrt{(\hbar v_{\parallel} k)^2 + \left(\frac{\hbar v_{\perp} (j + \Phi)}{R} \right)^2}$$

Surface state properties

- Spin-momentum locking changes dispersion compared to nanotubes!
 - Scattering of Kramers pair $[j + \Phi, k] \Leftrightarrow [-(j + \Phi), -k]$ forbidden (zero overlap of eigenstates!)
 - Gap vanishes for **half-integer flux** and special band $j = -\Phi$
 - spin-conserving single-particle back-scattering forbidden, protected against weak disorder
 - chemical potential near zero: precisely **one gapless helical mode**, effectively time reversal invariant ... **from now on we focus on this case!**
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Including interactions: Bosonization

- Chiral fermions with opposite spin

$$\Psi_{surf}(z, \phi) = \frac{1}{\sqrt{4\pi}} \left[e^{ik_F z} R(z) \begin{pmatrix} 1 \\ ie^{i\phi} \end{pmatrix} + e^{-ik_F z} L(z) \begin{pmatrix} -1 \\ ie^{i\phi} \end{pmatrix} \right]$$

- Bosonize: $(R/L)(z) \approx \frac{1}{\sqrt{2\pi\xi}} e^{i\sqrt{\pi}(\phi \pm \theta)}$
← surface layer width

- Spin momentum locking:

$$s_\phi = J = \frac{1}{\sqrt{\pi}} \partial_z \phi(z)$$

← dual boson fields

- Particle density: $\rho = \Psi^\dagger \Psi = \frac{1}{\sqrt{\pi}} \partial_z \theta$

Interacting helical Luttinger liquid

- Include Coulomb interaction
 - Helical liquid protected against weak disorder
 - Long-ranged Coulomb tail dominates
 - Hard-core interaction subdominant (marginal)
- **Single-mode helical Luttinger liquid**

$$H = \frac{\hbar u}{2} \int dz \left[K (\partial_z \varphi)^2 + K^{-1} (\partial_z \theta)^2 \right] \quad u = \frac{v_{\parallel}}{K}$$

- Interaction parameter K smaller than in HgTe:

$$K \approx \left(1 + \frac{2e^2}{\pi \epsilon v_{\parallel}} \left[0.51 + \ln \frac{L}{2\pi R} \right] \right)^{-1/2} \approx 0.4 \dots 0.5$$

Physical properties of helical LL

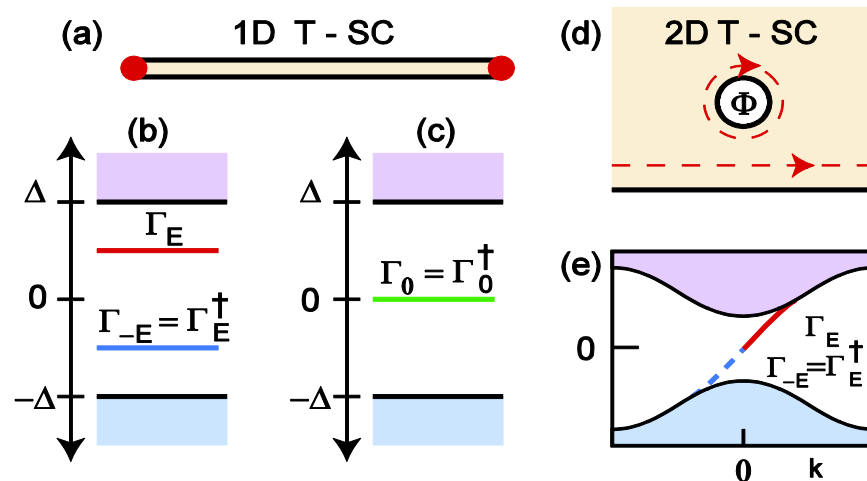
- **Anisotropic spin correlations** / RKKY interaction: Slow z^{-2K} power law decay with $2k_F$ oscillations in z direction
 - Formally: anisotropic SDW phase
- Linear conductance $G(T)$ very sensitive to presence of **magnetic impurities**

Maciejko et al., PRL 2009, Tanaka et al., PRL 2011

- Proximity induced superconductivity:
Majorana fermion states are induced at ends of TI nanowire

Cook & Franz, PRB 2012

Majorana fermions: end states of 1D topological superconductors



© Hasan & Kane, RMP 2010

- BdG Hamiltonian has particle-hole symmetry
- Quasiparticle operator for zero mode ($E=0$) state bound to the end of the TSC must be Majorana fermion: Quasiparticle is its own antiparticle
- Recently observed for InSb nanowires

Kouwenhoven group, Science Express 2012

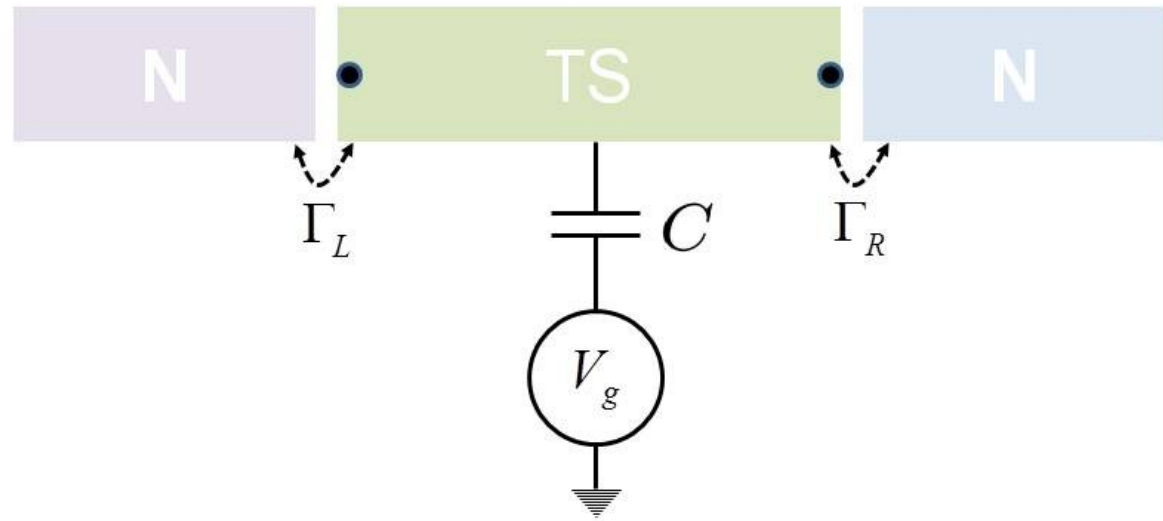
Coulomb blockade of Majorana fermion induced transport

Zazunov, Levy Yeyati & Egger,
PRB **84**, 165440 (2011)

Low-energy transport through topological superconductor wire with decoupled **Majorana end states** & source/drain metallic contacts

- Assume all energy scales small against proximity-induced gap, i.e., no quasiparticles on grain
- Zero mode Majorana fermions: $\gamma_{L/R} = \gamma_{L/R}^+$ $\{\gamma_i, \gamma_j\} = \delta_{ij}$
- Build auxiliary complex d fermion $d = \frac{1}{\sqrt{2}}(\gamma_L + i\gamma_R)$
- Assume „floating“ island (not grounded): current must be conserved

Schematic setup



With Cooper pair number operator N & conjugate phase ϕ :

➤ instantaneous dot state can be described by (N, n_d) with auxiliary fermion occupation $n_d = d^+ d = 0, 1$

Model

- Wire has electrostatic **charging energy**

$$H_c = E_C [2N + n_d - n_{gate}]^2$$

- Offset gate charge is continuous
- Full Hamiltonian: $H = H_c + H_t + H_{leads}$
- **Tunnel Hamiltonian**: source contact couples to γ_L & drain only to γ_R

$$H_t = \sum_k \left(\lambda_L c_{Lk}^+ [d + e^{-i\phi} d^+] - i\lambda_R c_{Rk}^+ [d - e^{-i\phi} d^+] \right) + h.c.$$

- **Fermi liquid leads**: Wide band approximation & Fermi functions with chemical potential $\mu_{L/R}$
- Hybridizations $\Gamma_{L/R} \sim \rho_0 |\lambda_{L/R}|^2$

Noninteracting solution: resonant Andreev reflection

- Solution for $E_c=0$:
$$I_{j=L/R}^{(0)} = \Gamma_j \int \frac{d\varepsilon}{2\pi} F(\varepsilon - \mu_j) A_j(\varepsilon)$$
- Fermi functions: lead distribution $F(\varepsilon) = \tanh(\varepsilon/2T)$
- Majorana spectral function
$$A_j(\varepsilon) = -\text{Im} G_j^{ret}(\varepsilon) = \frac{\Gamma_j}{\varepsilon^2 + \Gamma_j^2}$$
- Linear conductance @ $T=0$:
resonant Andreev reflection
$$G_{j=L/R} = \frac{e \partial I_j^{(0)}}{\partial \mu_j} = \frac{2e^2}{h}$$

Bolech & Demler, PRL 2007

Law, Lee & Ng, PRL 2009

Strong Coulomb blockade: Electron teleportation

Fu, PRL 2010

- Resonant case: half-integer n_{gate}
- Charging energy allows only two configurations
 - For $n_{gate}=1/2, 5/2, \dots$: fixed Cooper pair number N , states $n_d=0, 1$ degenerate
 - For $n_{gate}=3/2, 7/2, \dots$: $(N-1, 1)$ and $(N, 0)$ degenerate
- In both cases, model can be mapped to spinless **resonant tunneling** Hamiltonian
- Linear conductance ($T=0$): $G_{L/R} = e^2 / h$
- Fu's interpretation: **Electron teleportation**

Crossover from resonant Andreev reflection to electron teleportation

- Arbitrary charging energy: Keldysh approach with (Majorana-generalized) AES action
 - General expression: *Zazunov, Levy Yeyati & Egger, PRB 2011*
- Here study **weak Coulomb blockade** regime: interaction corrections to noninteracting result
- Full crossover from resonant Andreev reflection ($E_c=0$) to teleportation (large E_c) can be captured as well (**work in progress**)

Weak Coulomb blockade regime

- Phase fluctuations are small & allow for semiclassical expansion
- Keldysh-AES functional is then equivalent to **Langevin equation** for „classical“ phase

$$\ddot{\phi}_c + \Omega \dot{\phi}_c = \xi(t)$$

- Inverse RC time of effective circuit: $\Omega = \eta E_C$

- Dimensionless damping strength

$$\eta = \frac{2}{\pi} \sum_j \frac{\Gamma_j^2}{\mu_j^2 + \Gamma_j^2}$$

(higher energy scales: damping retardation!)

- Gaussian random force $\langle \xi(t) \xi(t') \rangle = 4E_C^2 K(t - t')$

How to obtain the current...

K has lengthy expression...

➤ **in equilibrium** satisfies fluctuation dissipation theorem

$$K_{eq}(\omega) = \frac{\omega}{2} \coth\left(\frac{\omega}{2T}\right) \eta_{eq}(\omega)$$

➤ **Current:**

$$I_j = \Gamma_j \int d\tau G_j^{ret}(\tau) \sin(\mu_j \tau) F(\tau) e^{-J(\tau)}$$

$$J(t-t') = \frac{1}{2} \left\langle [\bar{\phi}_c(t) - \bar{\phi}_c(t')]^2 \right\rangle_{\xi} \geq 0$$

solution $\bar{\phi}_c(t)$ for given noise realization

➤ **Some algebra:**

$$J(\tau) = \frac{1}{\pi \eta^2} \int_0^{\infty} d\omega K(\omega) \frac{1 - \cos \omega \tau}{\omega^2 (1 + \omega^2 / \Omega^2)}$$

➤ **Interactions always decrease current!**

Nonlinear conductance

- Symmetric system & $T=0$
- $$\mu_L = -\mu_R = eV / 2$$
- $$\Gamma_L = \Gamma_R = \Gamma / 2$$

- Observable:

$$g(V) = \frac{I(V)}{e^2 V / h}$$

- Noninteracting case (resonant Andreev reflection):

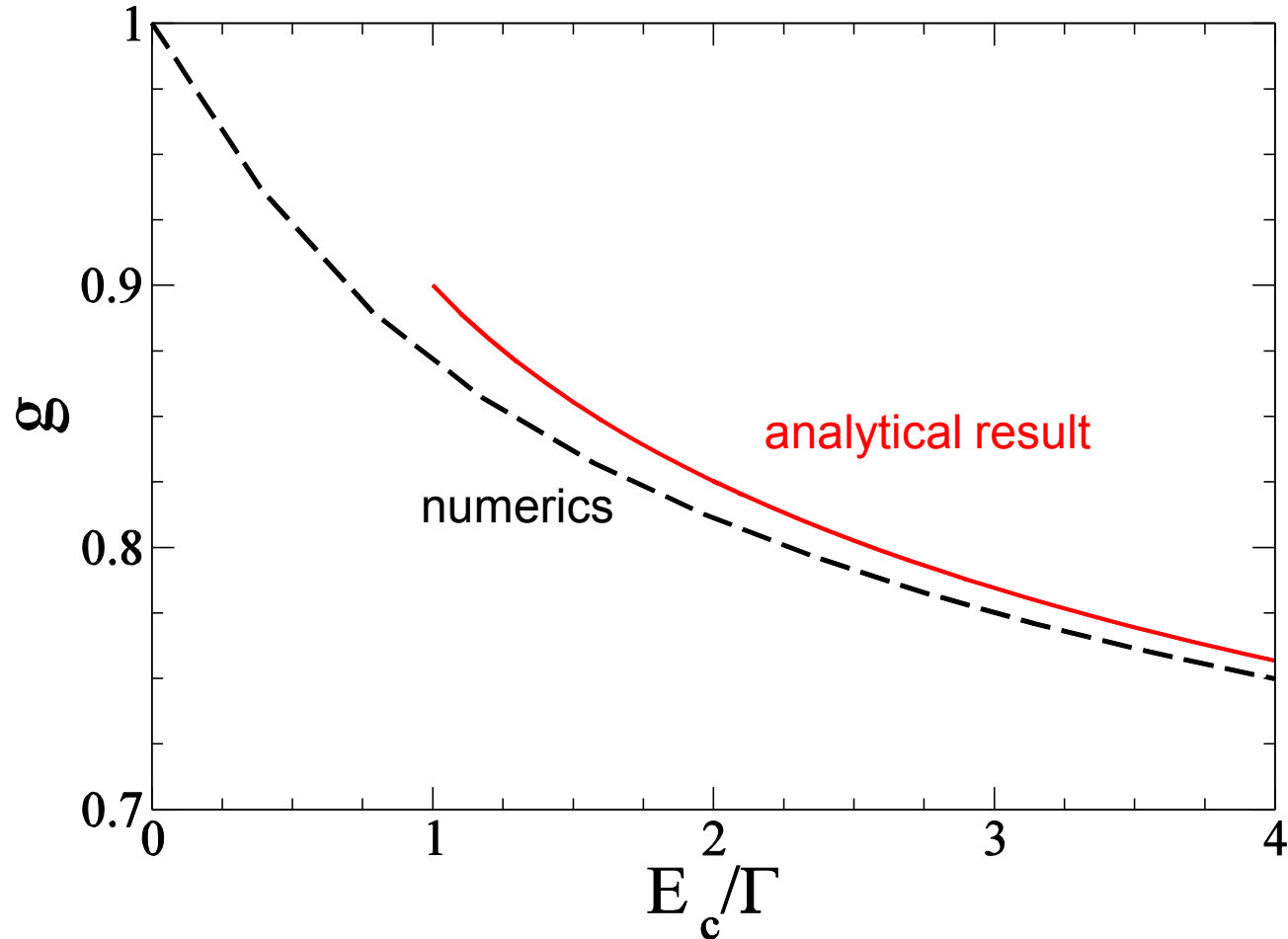
$$g^{(0)}(V) = \frac{\Gamma}{eV} \tan^{-1} \frac{eV}{\Gamma} \leq 1$$

- Analytical result for $\Gamma < E_C$: **universal power law suppression** of linear conductance with increasing charging energy

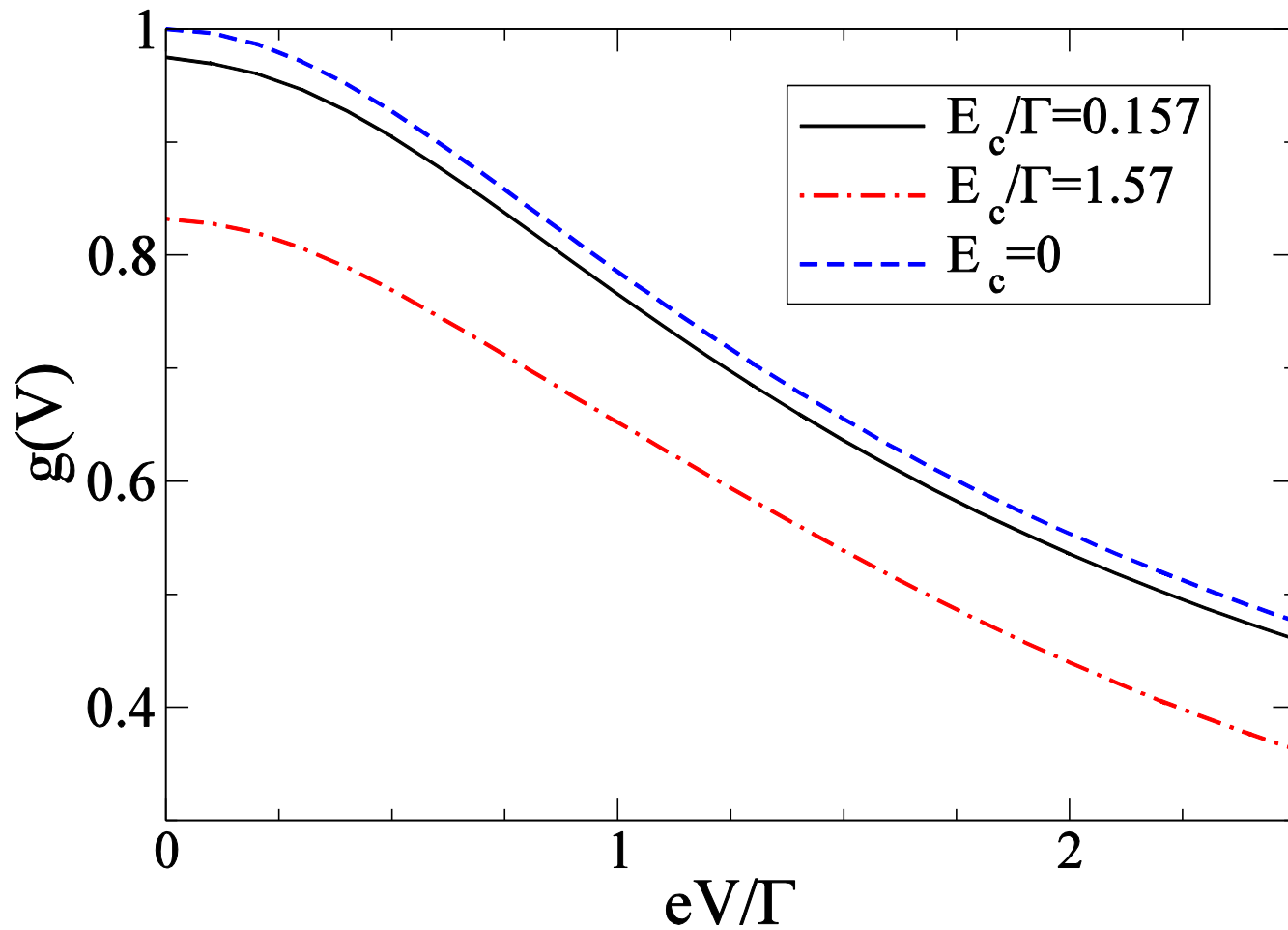
$$g(0) \approx 0.96 \left(\frac{E_C}{\Gamma} \right)^{-1/8}$$

Linear conductance: numerics

interaction induced suppression



Nonlinear conductance



Conclusions

- Topological insulators provide interesting playground for transport through interacting nanostructures
- TI nanowire as realization of single-mode helical Luttinger liquid with strong correlations

Egger, Zazunov & Levy Yeyati, PRL 105, 136403 (2010)

- Coulomb blockade in Majorana fermion induced transport: from resonant Andreev reflection to electron teleportation

Zazunov, Levy Yeyati & Egger, PRB 84, 165440 (2011)
